## NSN 5962-01-420-7500

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**Test Data Document:** 



View Online at https://aerobasegroup.com/nsn/5962-01-420-7500

Body Length:
0.358 inches
Body Width:
0.358 inches
Body Height:
0.100 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Hermetically sealed and burn in and programmable and positive outputs and electrostatic sensitive
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
C-2 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Program instruction (pal16r6a-2)
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Pal
Special Features:
Altered item, made from device 81036132x, cage 67268, program p/n 7816354p634 microcircuits, memory, programmable logic,
monolithic silicon

96906-mill-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:
20 leadless
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

No

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